## NSN 5962-01-414-5534

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N/a



View Online at https://aerobasegroup.com/nsn/5962-01-414-5534 **Body Length:** 0.460 inches **Body Width:** 0.460 inches **Body Height:** 0.100 inches **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** Pacer dawn **Features Provided:** Electrostatic sensitive and monolithic and tested to mil-std-883 **Inclosure Material:** Ceramic **Inclosure Configuration:** Leadless flat pack **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Criticality Code Justification:** Feat **Case Outline Source And Designator:** C-4 mil-m-38510 **Terminal Surface Treatment:** Solder **Product Name:** Microcircuits, digital, cmos 4k x4 sram with separate i/o monolithic s-ilicon **Voltage Rating And Type Per Characteristic:** 4.5 volts total supply and 5.5 volts total supply **Time Rating Per Chacteristic:** 45.00 nanoseconds access **Memory Device Type:** Ram **Special Features:** Esd **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 28 leadless Shelf Life:

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Demilitarization:

No

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